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Title:The dielectric behaviour of doped near-stoichiometric lithium niobate in the terahertz range Authors:Wu Liang (1); Ling Fu-Ri (1); Zuo Zhi-Gao (1); Liu Jin-Song (1); Yao Jian-Quan (1) Author affiliation:(1) Sch. of Optoelectron. Sci. & amp; Eng., Huazhong Univ. of Sci. & amp;

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Abstract:The dielectric properties of near-stoichiometric LiNbO₃:Fe and LiNbO₃:Ce single crystals have been investigated using terahertz time domain spectroscopy in a frequency range of 0.7-1.6 THz at room temperature. When coupled with an applied external optical field, obvious photorefractive effects were observed, resulting in a modulation of the complex dielectric constant for the crystals. The variation in refractive index, |Δn|, had a linear relationship with the applied light intensity, accompanied by a step-like decrease at high intensity. The findings were attributed to the internal space charge field of the photorefraction and the light-induced domain reversal in the crystals.

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Inspec controlled terms:cerium - doping - iron - lithium compounds - permittivity - photorefractive effect - refractive index - space charge - terahertz wave spectra

Uncontrolled terms:doped near-stoichiometric lithium niobate - dielectric properties - LiNbO₃:Fe single crystals - LiNbO₃:Ce single crystals - terahertz time domain spectroscopy - applied external optical field - photorefractive effects - complex dielectric constant modulation - refractive index variation - light intensity - internal space charge field - light-induced domain reversal - frequency 0.7 THz to 1.6 THz - temperature 293 K to 298 K - LiNbO₃:Fe - LiNbO₃:Ce

Inspec classification codes:A7720 Dielectric permittivity - A6170T Doping and implantation of impurities - A7870G Microwave and radiofrequency interactions with condensed matter - A7820D Optical constants and parameters (condensed matter) - A7750 Dielectric breakdown and space-charge effects - A7820W Other optical properties of condensed matter - B2810 Dielectric materials and properties

Numerical data indexing:frequency 7.0E+11 1.6E+12 Hz;temperature 2.93E+02 2.98E+02 K Chemical indexing:LiNbO3:Fe/ss LiNbO3/ss NbO3/ss O3/ss Fe/ss Li/ss Nb/ss O/ss Fe/el Fe/dop;LiNbO3:Ce/ss LiNbO3/ss NbO3/ss O3/ss Ce/ss Li/ss Nb/ss O/ss Ce/el Ce/dop Treatment:Experimental (EXP) Discipline:Physics (A); Electrical/Electronic engineering (B) DOI:10.1088/1674-1056/21/1/017802 Database:Inspec IPC Code:C30B31/00Copyright 2012, The Institution of Engineering and Technology